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Supplementary information

The measurement range of AFM 2D topography images in Figure 3c is consistent. We show in supplementary information that different AFM of Cs base tin-lead mixed perovskite and their RMS. Fig S1 shows the AFM of $CsPb_{0.75}Sn_{0.25}I_3$. And the RMS is 50.62 nm.



Fig S1. AFM top view and 3D topography images with $CsPb_{0.75}Sn_{0.25}I_3$

Fig S2 shows the AFM of $CsPb_{0.5}Sn_{0.5}I_{3.}$ And the RMS is 41.75 nm.



Fig S2. AFM top view and 3D topography images with CsPb_{0.5}Sn_{0.5}I₃

Fig S3 shows the AFM of $CsPb_{0.5}Sn_{0.5}I_3$. And the RMS is 51.43nm.



Fig S3. AFM top view and 3D topography images with CsPb_{0.25}Sn_{0.75}I₃

We measured XRD to determine the crystal structure parameters of the all-inorganic lead-tin mixed perovskite as follows.



Fig S4. XRD of $CsPb_{0.75}Sn_{0.25}I_3$, $CsPb_{0.5}Sn_{0.5}I_3$ and $CsPb_{0.25}Sn_{0.75}I_3$

Fig.S5 is the SEM cross-view and surface image of the all-inorganic perovskite solar cell with a lead-tin ratio of 0.25:0.75. From the figure, we can see that the crystal grains are larger.



Fig S5 SEM (a) cross-view and (b) surface with $CsPb_{0.25}Sn_{0.75}I_3$

Fig.S6 is the SEM cross-view and surface image of the all-inorganic perovskite solar cell with a lead-to-tin ratio of 0.5:0.5. From the figure, we can see that the grains are small and loose.



Fig S6 SEM (a) cross-view and (b) surface with CsPb_{0.5}Sn_{0.5}I₃

Fig.S7 is the SEM cross-view and surface image of the all-inorganic perovskite solar cell with a lead-tin ratio of 0.5:0.5. From the figure, we can see that the grains are smaller but denser.



Fig S7 SEM (a) cross-view and (b) surface with $CsPb_{0.75}Sn_{0.25}I_3$

Figure S8 shows the PL spectra of our measured lead-to-tin ratios of 0.75:0.25, 0.5:0.5, 0.25:0.75, and the emission band is about 850nm.



Figure S8. PL of $CsPb_{0.75}Sn_{0.25}I_3$, $CsPb_{0.5}Sn_{0.5}I_3$ and $CsPb_{0.25}Sn_{0.75}I_3$

	Bandgap	Process temperature (°C)	Process method	Year	Group
CsPbI ₃	~1.73 eV	335	Spin- coating	2015	H. Snaith ^[1]
CsPbI ₃	~1.73 eV		Quantum- dot	2016	J. Luther ^[2]
CsPbI ₂ Br	~1.92 eV	230	Spin- coating	2016	H. Snaith ^[3]
CsPbI ₂ Br	~1.92 eV	280	Spin- coating	2017	J. Park ^[4]
CsPbIBr ₂	~2.05 eV	250	Evaporation	2016	S. Huang ^[5]
CsPbIBr ₂	~2.05 eV	300	Spray	2016	A. Ho-Baillie ^[6]
CsPbI ₃	~1.72eV	100	Spin- coating	2017	J. Huang ^[7]
CsPb _{1-x} Bi _x I ₃	~1.55eV	100	Spin- coating	2017	S. Zhang ^[8]
CsPbI ₂ Br	~1.90eV	100	Spin- coating	2017	A. Ho-Baillie ^[9]
CsPb _{0.9} Sn _{0.1} IBr ₂	~1.79 eV		Spin- coating	2017	Z. Jin ^[10]
CsPbI ₃	~1.73 eV	150	Spin-	2017	Y. Zhao ^[11]

Table S1. Cs-based inorganic perovskite process temperature in previous publications

			coating		
CsPb _x Sn1 _{-x} I ₃	≤1.44 eV	100	Spin- coating	2017	This work